

Vishay General Semiconductor

SMD Photovoltaic Solar Cell Protection Rectifier



DO-214AB (SMC)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	5.0 A			
V _{RRM}	1000 V			
I _{FSM}	100 A			
I _R	10 μΑ			
V _F at I _F = 5.0 A	0.90 V			
T _J max.	150 °C			

FEATURES

- · Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in solar cell panel blocking diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: DO-214AB (SMC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test **Polarity:** Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	S5MS	UNIT	
Device marking code			5MS		
Maximum repetitive peak reverse voltage		V_{RRM}	1000	V	
Maximum DC fanuard ourrent (fig. 1)	T _M = 110 °C	l _F	5.0 ⁽¹⁾	А	
Maximum DC forward current (fig. 1)	T _A = 25 °C		1.6 (2)		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I _{FSM}	100	А	
Operating junction and storage temperature range		T _{OP} , T _{STG}	- 55 to + 150	°C	
Junction temperature in DC forward current without reverse bias, $t \le 1 \ h^{(3)}$		TJ	≤ 200	°C	

Notes

- (1) Mounted on 30 mm x 30 mm Al P.C.B.
- (2) Free air, mounted on recommended copper pad area
- $^{(3)}$ Meets the requirements of IEC 61215 Ed. 2 bypass diode thermal test

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ELECTRICAL CHARACTERISTICS (T = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage	I _F = 2.5 A	T _A = 25 °C	- V _F ⁽¹⁾	0.94	-	. V	
	I _F = 5.0 A			0.99	1.15		
	I _F = 2.5 A	T _A = 125 °C		0.82	-		
	I _F = 5.0 A			0.90	1.00		
Reverse current	Rated V _R	T _A = 25 °C	I _R ⁽²⁾	=	10	μА	
	nated v _R	T _A = 125 °C		50	250		
Maximum reverse recovery time	I _F = 0.5 A, I _R = I _{rr} = 0.25 A	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		2.5	-	μs	
Typical junction capacitance	4.0 V, 1 MHz	4.0 V, 1 MHz		40	-	pF	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	S5MS	UNIT		
Timing the average and interest	R _{0JA} (1)	92	°C/W		
Typical thermal resistance	R _{0JM} (2)	8			

Notes

- $^{(1)}$ Free air, mounted on recommended copper pad area. Thermal resistance $R_{\theta JA}$ junction to ambient
- $^{(2)}$ Mounted on 30 mm x 30 mm Al P.C.B. Thermal resistance $R_{\theta JM}$ junction to mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
S5MS-E3/57T	0.211	57T	850	7" diameter plastic tape and reel	
S5MS-E3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

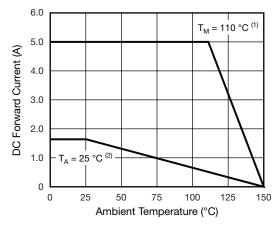


Fig. 1 - Forward Current Derating Curve

Notes

- $^{(1)}$ Mounted on 30 mm x 30 mm Al P.C.B. T_M measured at the terminal ($R_{\theta JM}=8~^{\circ}\text{C/W})$
- (2) Free air, mounted on recommended copper pad area ($R_{\theta JA} = 92$ °C/W)



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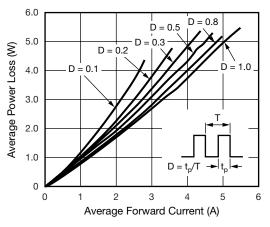


Fig. 2 - Forward Power Loss Characteristices

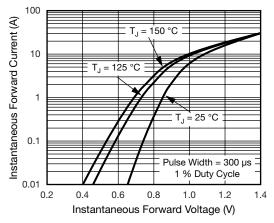


Fig. 3 - Typical Instantaneous Forward Characteristics

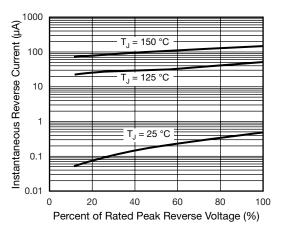


Fig. 4 - Typical Reverse Characteristics

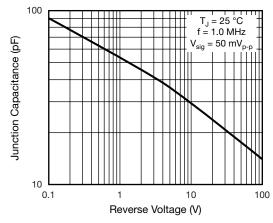


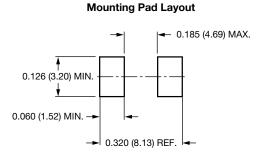
Fig. 5 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-214AB (SMC)

0.126 (3.20) 0.114 (2.90) 0.280 (7.11) 0.260 (6.60) 0.006 (1.52) 0.008 (0.2) 0.008 (0.2) 0.008 (0.2) 0.008 (0.2)

0.320 (8.13) 0.305 (7.75)





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